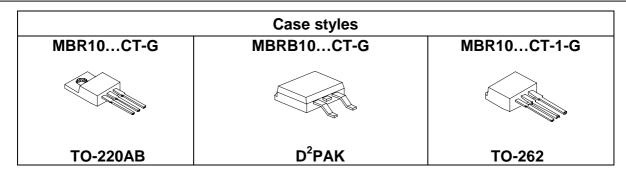
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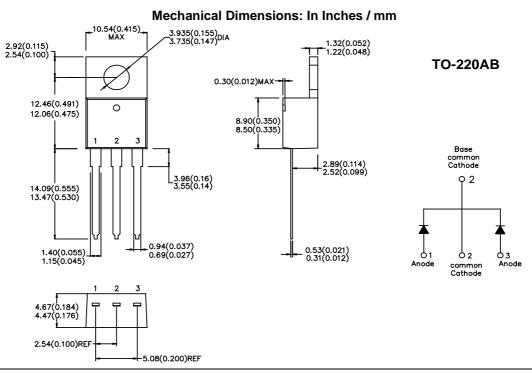
MBR1080CT-G/MBR1090CT-G/MBR10100CT-G SCHOTTKY RECTIFIER

Applications:

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection Features:

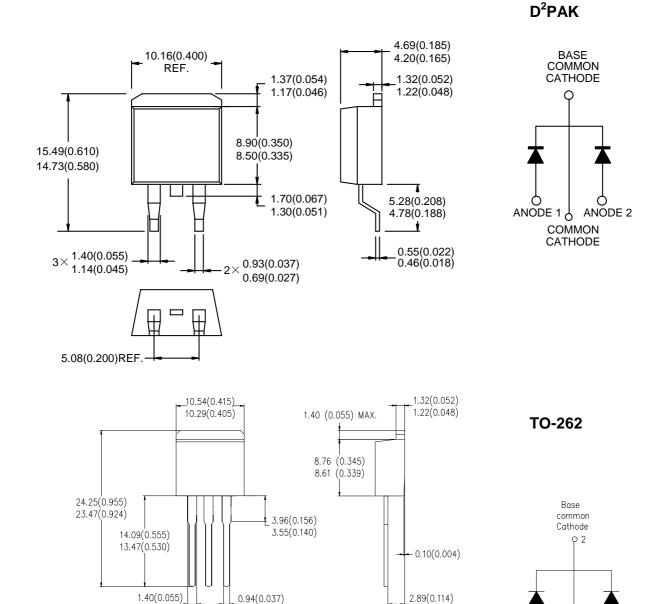
- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability

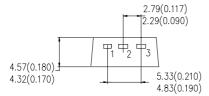




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 - World Wide Web Site http://www.sensitron.com E-Mail Address sales@sensitron.com •

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1.15(0.045)

0.94(0.037)

0.69(0.027)

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2.64(0.104)

9 common

Cathode

Anode

Anode

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MBR1080/90/100CT-G MBRB1080/90/100CT-G MBR1080/90/100CT-1-G

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Maximum Ratings:

Characteristics	Symbol	Condition		Max.	Units
Peak Inverse Voltage	V_{RWM}	-	80	MBR1080CT-G	V
				MBRB1080CT-G	
				MBR1080CT-1-G	
			90	MBR1090CT-G	
				MBRB1090CT-G	
				MBR1090CT-1-G	
			100	MBR10100CT-G	
				MBRB10100CT-G	
				MBR10100CT-1-G	
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C		5(Per leg)	Α
		=100°C, rectangular wave		10(Per device)	
		form			
Max. Peak One Cycle Non-					
Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse		120	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 5A, Pulse, T _J = 25 °C	0.85	V
(per leg) *		@ 10 A, Pulse, T _J = 25 °C	0.95	
	V_{F2}	@ 5 A, Pulse, T _J = 125 °C	0.75	V
		@ 10 A, Pulse, T _J = 125 °C	0.85	
Max. Reverse Current (per	I _{R1}	$@V_R = rated V_R$	1.00	mA
leg) *		T _J = 25 °C		
	I _{R2}	$@V_R = rated V_R$	15	mA
		T _J = 125 °C		
Max. Junction Capacitance	C _T	@V _R = 5V, T _C = 25 °C	300	pF
(per leg)		$f_{SIG} = 1MHz$		
Typical Series Inductance	L _S	Measured lead to lead 5 mm from	8.0	nΗ
(per leg)		package body		
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units	
Max. Junction Temperature	T_J	-	-55 to +150	°C	
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C	
Maximum Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	2.0	°C/W	
Maximum Thermal Resistance, Case to Heat Sink	$R_{\theta CS}$	Mounting surface, smooth and greased (only for TO-220)	0.50	°C/W	
Approximate Weight	wt	-	2	g	
Mounting Torque	T _M	-	6(Min.) 12(Max.)	Kg-cm	
Case Style	TO-220AB D ² PAK TO-262				

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MBR1080/90/100CT-G MBRB1080/90/100CT-G MBR1080/90/100CT-1-G

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